NSN 5961-01-012-8201

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-012-8201 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.086 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 breakdown voltage, dc **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 1.2 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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